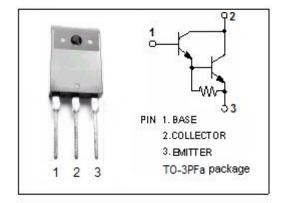


isc Silicon NPN Darlington Power Transistor

DESCRIPTION

- · High DC Current Gain-
- : h_{FE}= 5000(Min)@I_C= 6A
- · Low-Collector Saturation Voltage-
- : V_{CE(sat)}= 2.5V(Max.)@I_C= 6A
- · Complement to Type 2SB1254
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

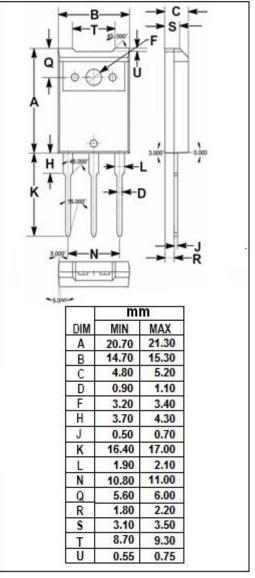


APPLICATIONS

· Designed for power amplifier applications

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V_{CBO}	Collector-Base Voltage	160	V	
V _{CEO}	Collector-Emitter Voltage	140	V	
V _{EBO}	Emitter-Base Voltage	5	V	
lc	Collector Current-Continuous	7	Α	
Ісм	Collector Current-Peak	12	Α	
D	Collector Power Dissipation @ T _C =25℃	70	W	
P _C	Collector Power Dissipation @ T _a =25 °C	3	VV	
TJ	Junction Temperature 150		$^{\circ}\mathbb{C}$	
T _{stg}	Storage Temperature Range -55~150		$^{\circ}$	





isc Silicon NPN Darlington Power Transistor

2SD1894

ELECTRICAL CHARACTERISTICS

 T_{C} =25°C unless otherwise specified

.0 20 0 4								
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 30mA; I _B = 0	140			V		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 6A; I _B = 6mA			2.5	V		
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 6A; I _B = 6mA			3.0	V		
Ісво	Collector Cutoff Current	V _{CB} = 160V; I _E = 0			100	μА		
ICEO	Collector Cutoff Current	V _{CE} = 140V; I _B = 0			100	μА		
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			100	μА		
h _{FE-1}	DC Current Gain	I _C = 1A; V _{CE} = 5V	2000					
h _{FE-2}	DC Current Gain	I _C = 6A; V _{CE} = 5V	5000		30000			
f _T	Current-Gain—Bandwidth Product	I _C = 0.5A; V _{CE} = 10V		20		MHz		
Switching Times								
ton	Turn-on Time			2.5		μ S		
t _{stg}	Storage Time	I_{C} = 6A; I_{B1} = I_{B2} = 6mA, V_{CC} = 50V		5.0		μ S		
t _f	Fall Time			2.5		μ S		

♦ h_{FE-2} Classifications

Q	Р		
5000-15000	8000-30000		

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